

**SPECIFICATION AMENDMENTS:**

Amend paragraph [0001] as follows:

[0001] This application is a division of co-pending U.S. Patent Application Serial No. 09/849,036 entitled “High Voltage Power MOSFET Having Low On-Resistance,” filed on May 4, 2001, which is a continuation-in-part of U.S. Appl. Serial No. 09/586,407, entitled “High Voltage Power MOSFET Having Low On-Resistance,” filed on June 2, 2000.